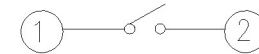
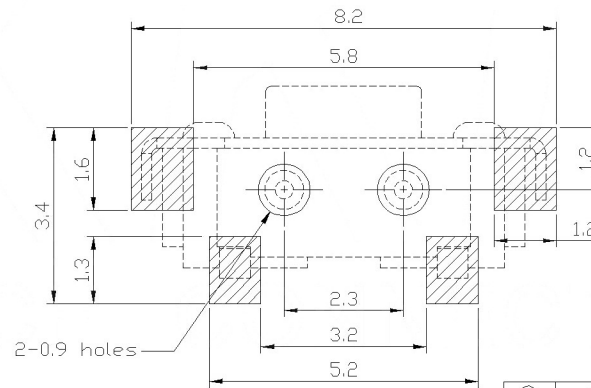
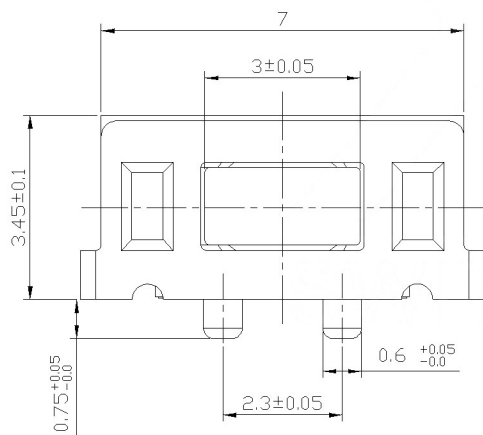


CIRCUIT DIAGRAM



SPECIFICATION

Contact Rating : 50mA,12V DC
 Contact Resistance : 100mΩ max
 Insulation Resistance : 100mΩ min,500V DC
 Dielectric Strength : 250V AC/1minute
 Travel : 0.25mm
 Operating Temp : -30°C~+85°C
 Storage Temp : -30°C~+80°C



PAPT NO	TS-1101VS-X-X-B
Operating Force	A: 100gf B: 160gf C: 260gf
Height	H: 3.5
Fixed column	A:With B:without
Keystake	A: PA46 B: Silica gel

ITEM	PAPT NAMF	TER,NO	QTY	MATERIAL	FINISHING	REMARK
⑤	Terminal	—	2	Brass (0.30t)	Plating silvering	—
④	Contact	—	1	F.ag/Sus	Natural	—
③	Base	—	1	Lcp	—	—
②	Cover	—	1	Brass	Plating Nickel	—
①	Keystake	—	1	Silica gel	—	—

MARK	DESCRIPTION	DATE	REVISED	APPROVED	UNSPECIFIED TOLERANCES
Δx					units: mm
Δx					tolerance: X.X ±0.2mm
Δx					X.XX ±0.1mm
MARK					X.XXX ±0.05mm

DSND	DATE	SCALE: N/A	MODEL TYPE:
DWN	DATE	VIEW:	TACT SWITCH
CHKD	DATE	UNIT: mm	PART NO.:
APPD	DATE	SIZE: A4	DWG NO.: TS-1101VS-X-X-B
Kosod Technology Co., Ltd.			WEIGHT SHEET REVISION
			1.0g 1/1 A0